









LM2767 JAJSNR6E - FEBRUARY 2000 - REVISED JANUARY 2022

LM2767 スイッチド・コンデンサ電圧コンバータ

1 特長

- 入力電源電圧が2倍に向上
- SOT-23 5 ピン・パッケージで供給
- 出力インピーダンス:20Ω (標準値)
- 標準変換効率 96% (15mA 時)

2 アプリケーション

- 携帯電話
- ページャ
- PDA、オーガナイザ
- オペアンプの電源
- インターフェイス電源
- ハンドヘルド機器

3 概要

LM2767 CMOS チャージ・ポンプ電圧コンバータは、 1.8V~5.5V の入力電圧範囲で電圧ダブラーとして動作 します。この回路では、低コストな2つのコンデンサとダイ オードを使用して、15mA以上の出力電流を供給します。

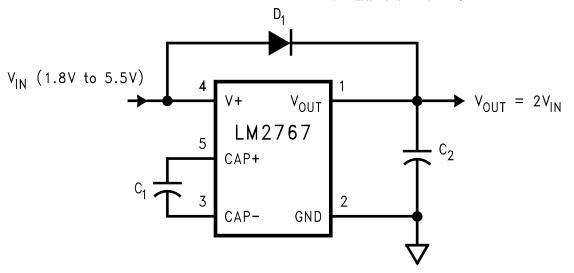
LM2767 は 11kHz のスイッチング周波数で動作するた め、オーディオ音声帯域干渉を回避できます。動作電流 がわずか 40µA (ほとんどの負荷で 90% 以上の動作効 率) であるため、LM2767 はバッテリ駆動システムに最適 な性能を発揮します。このデバイスは5ピン

SOT-23 パッケージで供給されます。

製品情報

	-4 II II II II						
部品番号		パッケージ ⁽¹⁾	本体サイズ (公称)				
	LM2767	SOT-23 (5)	2.90mm × 1.60mm				

利用可能なパッケージについては、このデータシートの末尾にあ る注文情報を参照してください。



代表的なアプリケーション



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	料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。	
C	hanges from Revision D (August 2015) to Revision E (January 2022)	Page
	文書全体の表、図、相互参照の番号形式を更新Added additional I _L specification test condition	
C	hanges from Revision C (May 2013) to Revision D (August 2015)	Page
•	「デバイス情報」、「ピン構成および機能」セクション、ESD 定格表、「機能説明」、「デバイスの機能モード」、「アフーションと実装」、「電源に関する推奨事項」、「レイアウト」、「デバイスおよびドキュメントのサポート」、「メカニカルケージ、および注文情報」セクションを追加	、パッ

5 Pin Configuration and Functions

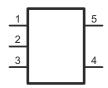


図 5-1. DBV Package 5-Pin SOT-23 Top View

表 5-1. Pin Functions

PIN		TYPE	DESCRIPTION	
NUMBER	NAME	IIFE	DESCRIP HON	
1	VOUT	Power	Positive voltage output.	
2	GND	Ground	Power supply ground input.	
3	CAP-	Power	Connect this pin to the negative terminal of the charge-pump capacitor.	
4	V+	Power	Power supply positive voltage input.	
5	CAP+	Power	Connect this pin to the positive terminal of the charge-pump capacitor.	



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1) (2)

	MIN	MAX	UNIT
Supply voltage (V+ to GND, or V+ to V _{OUT})		5.8	V
V _{OUT} continuous output current		30	mA
Output short-circuit duration to GND ⁽³⁾		1	sec
Continuous power dissipation (T _A = 25°C) ⁽⁴⁾		400	mW
T _{JMax} ⁽⁴⁾		150	°C
Storage temperature, T _{stg}	-65	150	°C

- (1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) If Military/Aerospace specified devices are required, contact the TI Sales Office/ Distributors for availability and specifications.
- (3) V_{OUT} may be shorted to GND for one second without damage. For temperatures above 85°C, V_{OUT} must not be shorted to GND or device may be damaged.
- (4) The maximum allowable power dissipation is calculated by using $P_{DMax} = (T_{JMax} T_A)/R_{\theta JA}$, where T_{JMax} is the maximum junction temperature, T_A is the ambient temperature, and $T_{\theta JA}$ is the junction-to-ambient thermal resistance of the specified package.

6.2 ESD Ratings

			VALUE	UNIT
V	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	V
V _(ESD)	Liectiostatic discriarge	Machine model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±200	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

	MIN	NOM	MAX	UNIT
Junction temperature	-40		100	°C
Ambient temperature	-40		85	°C
Lead temperature (soldering, 10 sec.)			240	°C

6.4 Thermal Information

	LM2767	
THERMAL METRIC(1)	DBV (SOT-23)	UNIT
	5 PINS	
R _{θJA} Junction-to-ambient thermal resistance	210	°C/W

 For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

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6.5 Electrical Characteristics

Unless otherwise specified, typical limits are for T_J = 25°C, minimum and maximum limits apply over the full operating temperature range: V+ = 5 V, C_1 = C_2 = 10 μ F.⁽¹⁾

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V+	Supply voltage		1.8		5.5	V
IQ	Supply current	No load		40	90	μA
IL	Output current	2.5 V ≤ V+ ≤ 5.5 V	15			mA
		1.8 V ≤ V+ < 2.5 V	10			mA
R _{OUT}	Output resistance ⁽²⁾	I _L = 15 mA		20	40	Ω
$f_{\sf OSC}$	Oscillator frequency	See ⁽³⁾	8	22	50	kHz
$f_{\sf SW}$	Switching frequency	See ⁽³⁾	4	11	25	kHz
В	Power efficiency	R_L (5 k Ω) between GND and OUT		98%		
P _{EFF}	Fower eniciency	I _L = 15 mA to GND		96%		
V _{OEFF}	Voltage conversion efficiency	No load		99.96%		

⁽¹⁾ In the test circuit, capacitors C_1 and C_2 are $10-\mu F$, $0.3-\Omega$ maximum ESR capacitors. Capacitors with higher ESR may increase output resistance, and reduce output voltage and efficiency.

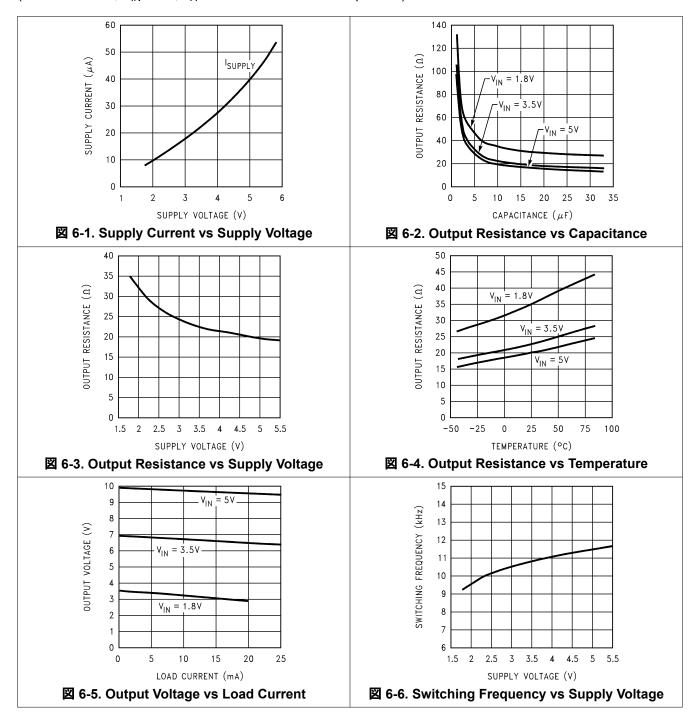
⁽²⁾ Specified output resistance includes internal switch resistance and capacitor ESR. See the details in セクション 9 for positive voltage doubler.

⁽³⁾ The output switches operate at one half of the oscillator frequency, $f_{\rm OSC}$ = 2 × $f_{\rm SW}$.

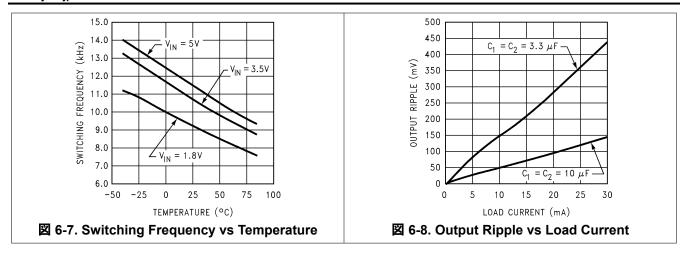


6.6 Typical Characteristics

(Circuit of \boxtimes 7-1, V_{IN} = 5 V, T_A = 25°C unless otherwise specified).



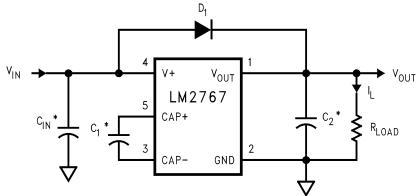
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7 Parameter Measurement Information

7.1 Test Circuit



* $\mathrm{C_{IN}}$, $\mathrm{C_{1}}$, and $\mathrm{C_{2}}$ are 10 $\mu\mathrm{F}$ OS-CON capacitors.

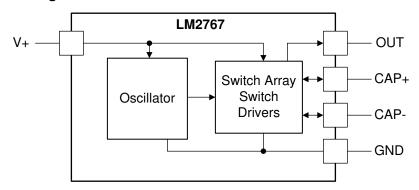
図 7-1. LM2767 Test Circuit

8 Detailed Description

8.1 Overview

The LM2767 CMOS charge-pump voltage converter operates as a voltage doubler for an input voltage in the range of 1.8 V to 5.5 V. Two low-cost capacitors and a diode (needed during start-up) are used in this circuit.

8.2 Functional Block Diagram



8.3 Feature Description

The LM2767 contains four large CMOS switches which are switched in a sequence to double the input supply voltage. Energy transfer and storage are provided by external capacitors. \boxtimes 9-2 illustrates the voltage conversion scheme. When S₂ and S₄ are closed, C₁ charges to the supply voltage V+. During this time interval, switches S₁ and S₃ are open. In the next time interval, S₂ and S₄ are open; at the same time, S₁ and S₃ are closed, the sum of the input voltage V+ and the voltage across C₁ gives the 2V+ output voltage when there is no load. The output voltage drop when a load is added is determined by the parasitic resistance (R_{ds(on)} of the MOSFET switches and the ESR of the capacitors) and the charge transfer loss between capacitors. Details are discussed in \not 9.

8.4 Device Functional Modes

The LM2767 is always enabled when power is applied to the V+ pin (1.8 V \leq V_{IN} \leq 5.5 V). To disable the part, power must be removed.

9 Application and Implementation

Note

以下のアプリケーション情報は、TIの製品仕様に含まれるものではなく、TIではその正確性または完全性を保証いたしません。個々の目的に対する製品の適合性については、お客様の責任で判断していただくことになります。お客様は自身の設計実装を検証しテストすることで、システムの機能を確認する必要があります。

9.1 Application Information

The LM2767 provides a simple and efficient means of creating an output voltage level equal to twice that of the input voltage. Without the need of an inductor, the application solution size can be reduced versus the magnetic DC-DC converter solution.

9.2 Typical Application

The main application of the LM2767 is to double the input voltage. The range of the input supply voltage is 1.8 V to 5.5 V.

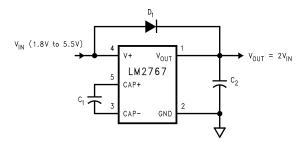


図 9-1. LM2767 Typical Application

9.2.1 Design Requirements

For typical switched-capacitor voltage converter applications, use the parameters listed in 表 9-1.

表 9-1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE	
Minimum input voltage	1.8 to 5.5 V	
Output current (minimum)	15 mA	
Switching frequency	11 kHz (typical)	

9.2.2 Detailed Design Procedure

9.2.2.1 Positive Voltage Doubler

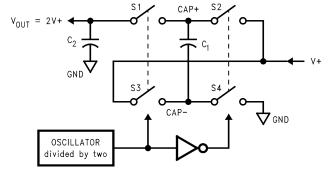


図 9-2. Voltage Doubling Principle

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The output characteristics of this circuit can be approximated by an ideal voltage source in series with a resistance. The voltage source equals 2 V+. The output resistance Rout is a function of the ON resistance of the internal MOSFET switches, the oscillator frequency, and the capacitance and ESR of C₁ and C₂. Because the switching current charging and discharging C₁ is approximately twice the output current, the effect of the ESR of the pumping capacitor C_1 is multiplied by four in the output resistance. The output capacitor C_2 is charging and discharging at a current approximately equal to the output current, therefore, its ESR only counts once in the output resistance. A good approximation of Rout is:

$$R_{OUT} \cong 2R_{SW} + \frac{2}{f_{OSC} \times C_1} + 4ESR_{C1} + ESR_{C2}$$
(1)

where

The peak-to-peak output voltage ripple is determined by the oscillator frequency as well as the capacitance and ESR of the output capacitor C₂:

$$V_{RIPPLE} = \frac{I_L}{f_{OSC} \times C_2} + 2 \times I_L \times ESR_{C2}$$
 (2)

High capacitance, low ESR capacitors can reduce both the output resistance and the voltage ripple.

The Schottky diode D₁ is only needed to protect the device from turning on its own parasitic diode and potentially latching up. During start-up, D₁ also quickly charges up the output capacitor to V_{IN} minus the diode drop thereby decreasing the start-up time. Therefore, the Schottky diode D₁ must have enough current carrying capability to charge the output capacitor at start-up, as well as a low forward voltage to prevent the internal parasitic diode from turning on. A Schottky diode like 1N5817 can be used for most applications. If the input voltage ramp is less than 10 V/ms, a smaller Schottky diode like MBR0520LT1 can be used to reduce the circuit size.

9.2.2.2 Capacitor Selection

As discussed in セクション 9.2.2.1, the output resistance and ripple voltage are dependent on the capacitance and ESR values of the external capacitors. The output voltage drop is the load current times the output resistance, and the power efficiency is

$$\eta = \frac{P_{\text{OUT}}}{P_{\text{IN}}} = \frac{I_{\text{L}}^2 R_{\text{L}}}{I_{\text{L}}^2 R_{\text{L}} + I_{\text{L}}^2 R_{\text{OUT}} + I_{\text{Q}}(V+)}$$
(3)

where

- I_Q(V+) is the quiescent power loss of the device; and
- I_L $^2R_{out}$ is the conversion loss associated with the switch on-resistance, the two external capacitors and their

The selection of capacitors is based on the allowable voltage droop (which equals Iout Rout), and the desired output voltage ripple. Low-ESR capacitors (表 9-2) are recommended to maximize efficiency, reduce the output voltage drop and voltage ripple.

表 9-2. Low-ESR Capacitor Manufacturers

MANUFACTURER	PHONE	WEBSITE	CAPACITOR TYPE			
Nichicon Corp.	(847)-843-7500	www.nichicon.com	PL & PF series, through-hole aluminum electrolytic			
AVX Corp.	(843)-448-9411	www.avxcorp.com TPS series, surface-mount tantalum				
Sprague	(207)-324-4140	www.vishay.com	593D, 594D, 595D series, surface-mount tantalum			
Sanyo	(619)-661-6835	www.sanyovideo.com	OS-CON series, through-hole aluminum electrolytic			
Murata	(800)-831-9172	www.murata.com	Ceramic chip capacitors			
Taiyo Yuden	(800)-348-2496	www.t-yuden.com	Ceramic chip capacitors			

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表 9-2. Low-ESR Capacitor Manufacturers (continued)

MANUFACTURER	PHONE	WEBSITE	CAPACITOR TYPE
Tokin	(408)-432-8020	www.tokin.com	Ceramic chip capacitors

9.2.2.3 Paralleling Devices

Any number of LM2767 devices can be paralleled to reduce the output resistance. Because there is no closed loop feedback, as found in regulated circuits, stable operation is assured. Each device must have its own pumping capacitor C_1 , while only one output capacitor C_{OUT} is needed as shown in \boxtimes 9-3. The composite output resistance is:

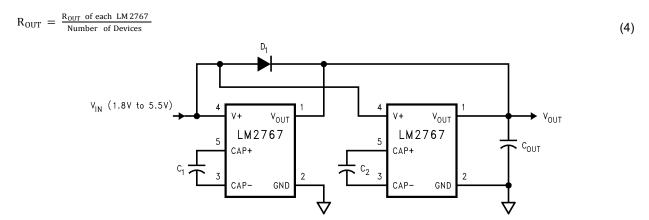


図 9-3. Lowering Output Resistance by Paralleling Devices

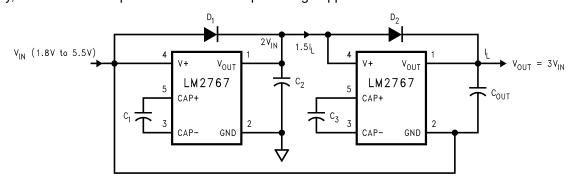
9.2.2.4 Cascading Devices

Cascading the several LM2767 devices is an easy way to produce a greater voltage (a two-stage cascade circuit is shown in 🗵 9-4).

The effective output resistance is equal to the weighted sum of each individual device:

$$R_{OUT} = 1.5 R_{OUT \ 1} + R_{OUT \ 2}$$
 (5)

Note that increasing the number of cascading stages is practically limited because it significantly reduces the efficiency, increases the output resistance and output voltage ripple.



☑ 9-4. Increasing Output Voltage By Cascading Devices

9.2.2.5 Regulating V_{OUT}

It is possible to regulate the output of the LM2767 by use of a low dropout regulator (such as LP2980-5.0). The whole converter is depicted in \boxtimes 9-5.

A different output voltage is possible by use of LP2980-3.3, LP2980-3.0, or LP2980-ADJ.

The following conditions must be satisfied simultaneously for worst case design:

$$2V_{IN_MIN} > V_{OUT_MIN} + V_{DROP_MAX} (LP2980) + I_{OUT_MAX} \times R_{OUT_MAX}$$
 (6)

$$2V_{\text{IN MAX}} < V_{\text{OUT MAX}} + V_{\text{DROP MIN}} (\text{LP2980}) + I_{\text{OUT MIN}} \times R_{\text{OUT MIN}}$$
 (7)

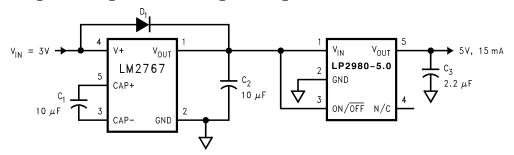


図 9-5. Generate a Regulated 5-V From 3-V Input Voltage

9.2.3 Application Curve

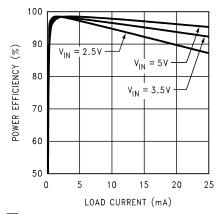


図 9-6. Efficiency vs Load Current



10 Power Supply Recommendations

The LM2767 is designed to operate from as an inverter over an input voltage supply range from 1.8 V and 5.5 V. This input supply must be well-regulated and capable to supply the required input current. If the input supply is located far from the device, additional bulk capacitance may be required in addition to the ceramic bypass capacitors.

11 Layout

11.1 Layout Guidelines

Use the following steps as a reference to ensure the device is stable across its intended operating voltage and current range.

- Place CIN on the top layer (same layer as the LM2767) and as close to the device as possible. Connecting
 the input capacitor through short, wide traces to both the V+ and GND pins reduces the inductive voltage
 spikes that occur during switching which can corrupt the V+ line.
- Place COUT on the top layer (same layer as the LM2767) and as close as possible to the OUT and GND pin.
 The returns for both CIN and COUT must come together at one point, as close to the GND pin as possible.
 Connecting COUT through short, wide traces reduce the series inductance on the OUT and GND pins that can corrupt the VOUT and GND lines and cause excessive noise in the device and surrounding circuitry.
- Place C1 on the top layer (same layer as the LM2767 device) and as close to the device as possible. Connect the flying capacitor through short, wide traces to both the CAP+ and CAP- pins.

11.2 Layout Example

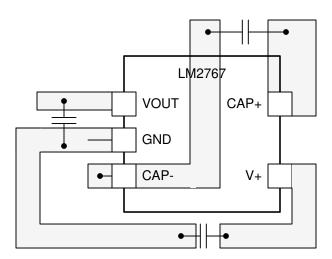


図 11-1. LM2767 Layout Example



12 Device and Documentation Support

12.1 Device Support

12.1.1 Third-Party Products Disclaimer

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12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.3 サポート・リソース

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12.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
LM2767M5	Active	Production	SOT-23 (DBV) 5	1000 LARGE T&R	No	SNPB	Level-1-260C-UNLIM	-40 to 85	S17B
LM2767M5.A	Active	Production	SOT-23 (DBV) 5	1000 LARGE T&R	No	SNPB	Level-1-260C-UNLIM	-40 to 85	S17B
LM2767M5.B	Active	Production	SOT-23 (DBV) 5	1000 LARGE T&R	No	SNPB	Level-1-260C-UNLIM	-40 to 85	S17B
LM2767M5/NOPB	Active	Production	SOT-23 (DBV) 5	1000 SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	S17B
LM2767M5/NOPB.A	Active	Production	SOT-23 (DBV) 5	1000 SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	S17B
LM2767M5/NOPB.B	Active	Production	SOT-23 (DBV) 5	1000 SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	S17B
LM2767M5X/NOPB	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	S17B
LM2767M5X/NOPB.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	S17B
LM2767M5X/NOPB.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	S17B

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽³⁾ RoHS values: Yes, No. RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



PACKAGE OPTION ADDENDUM

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and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

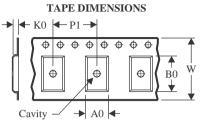
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

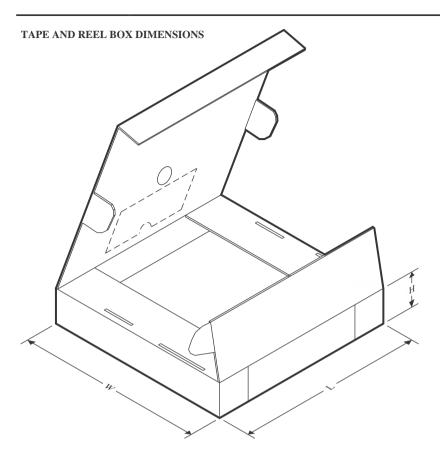
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM2767M5/NOPB	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM2767M5X/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins SPQ		Length (mm)	Width (mm)	Height (mm)	
LM2767M5/NOPB	SOT-23	DBV	5	1000	210.0	185.0	35.0	
LM2767M5X/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0	



SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
 3. Reference JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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最終更新日: 2025 年 10 月